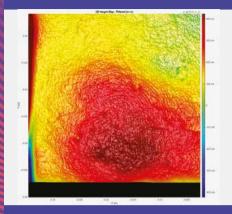
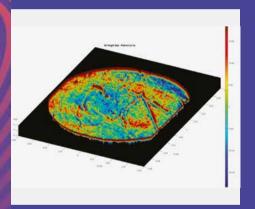
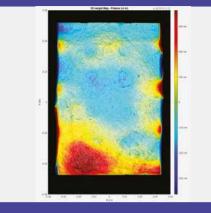
D-SURFACE TESTING SAMPLES



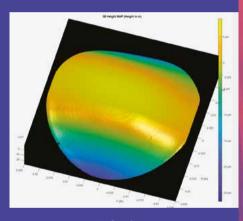
Phone fingerprint



Wafer roughness



Phone screen



Wafer shape

Deflectometry-based Surface Inspection & Flatness measurement

Local and Global inspection nm to mm

One shot measurement

Down to nanometer scale

Measurement that goes beyond limits

CONTACT
sales@dip-view.com
Toulouse • France



SURFACE

FEATURES

Vertical dynamic range 1 nm to 1mm

Field of view up to 300mm

Lateral resolution down to 10um

Full diameter measurement of the sample without stitching 1 shot measurement

> Software Easy-to-use software interface

APPLICATIONS

Texture 2D and 3D roughness and waviness

> Form 2D and 3D bow and shape

Stress 2D and 3D thin film stress

Defect review 2D and 3D defect surface topography

INDUSTRIES

Universities, research labs, and institutes

Semiconductor and compound semiconductor

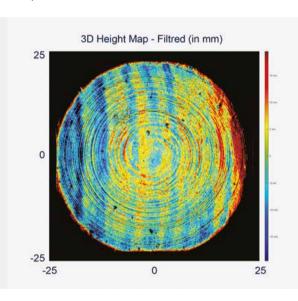
Solar

LED Manufacturing

Data storage Automotive Medical devices **D-Surface View** is intended to help manufacturers of wafers up to 300-mm diameter reduce costs and chipmakers to improve yields for devices made with finest process technology.

The equipment can be used for wafer surface quality control, it qualifies surface roughness, shape, flatness and topography in one single measurement of a bare or processed wafer.

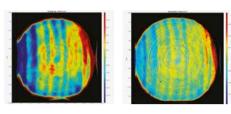
Its very high resolution performances bring fast, reliable and highly sensitive solution particularly adapted to off-line or in-line, surface local / global inspections in multiple industries.



OFFLINE ANALYSIS SOFTWARE

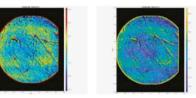
- > 2D and 3D step heights with cursors and histography analysis
- > 2D profiles and 3D views of the measurements
- > 2D and 3D roughness and waviness analysis
- > 2D and 3D filtering and leveling techniques
- > Thin film stress and sample bow calculation

MEASUREMENT APPLICATIONS



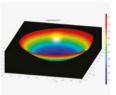
Texture: Roughness and Waviness

Measure 2D and 3D texture while quantifying the sample's roughness and waviness. Distinguish between roughness and waviness components using software filters.



Defect Analysis

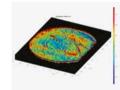
Measure the topography of defects, such as the depth of a scratch





Form: Bow and Shape

Measure the 2D shape or bow of a surface. Quantify the height and radius of curved structures, such as a lens.



Thin Film Stress

Measure 2D stress induced during the manufacture of semiconductor or compound semiconductor devices having multiple process layers.

TECHNICAL CHARACTERISTICS

	D-Surface View 100	D-Surface View 200	D-Surface View 300
Measuring surface	100 × 100 mm² (flat object)	200 × 200 mm² (flat object)	300 × 300 mm² (flat object)
Out of plane tolerance	+/- 1mm	+/- 2mm	+/- 3-4mm
Lateral resolution	22 µm	44 µm	66 µm
Vertical resolution	<1 nm	1-2 nm	2 nm
Measurement time	typ.1 sec	typ.1 sec	typ.1 sec
Repeatability	<0,05 nm rms	<0,05 nm rms	<0,05 nm rms
Cameras	20 MPixels	20 MPixels	20 MPixels
Outer dimensions W × H × D	400 × 300 × 300 mm³	450 × 600 × 400 mm³	500 x 900 x 500 mm ³